

## Hysteretic, Buck, High Brightness LED Driver with High-Side Current Sensing

### Features

- Hysteretic control with high-side current sensing
- Wide input-voltage range: 4.5 to 40V
- >90% Efficiency
- Typical  $\pm 5\%$  LED current accuracy
- Up to 2.0MHz switching frequency
- Adjustable constant LED current
- Analog or PWM control signal for PWM dimming
- Over-temperature protection
- $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  operating temperature range

### Applications

- Low-voltage industrial and architectural lighting
- General purpose constant current source
- Signage and decorative LED lighting
- Indicator and emergency lighting

### Description

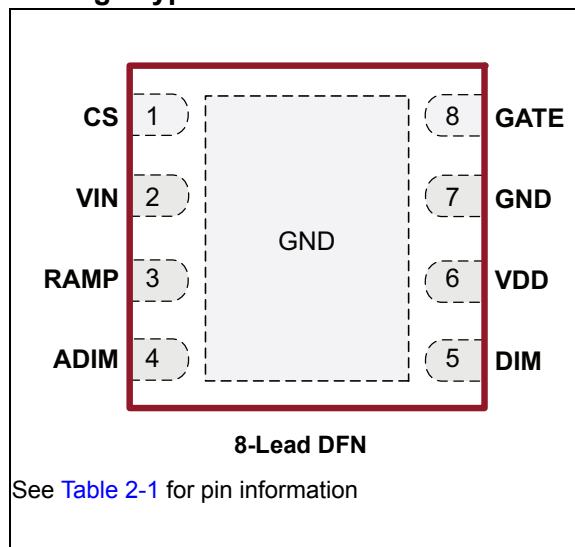
HV9919B is a Pulse-Width Modulation (PWM) controller IC designed to drive high-brightness LEDs using a buck topology. It operates from an input voltage of 4.5 to 40VDC and employs hysteretic control, with a high-side current sense resistor, to set the constant output current.

Set the operating frequency range by selecting the proper inductor. Operation at high switching frequency is possible since the hysteretic control maintains accuracy even at high frequencies. This permits the use of small inductors and capacitors, minimizing space and cost in the overall system.

LED brightness control is achieved with PWM dimming from an analog or PWM input signal. Unique PWM circuitry allows true constant color with a high dimming range. The dimming frequency is programmed using a single external capacitor.

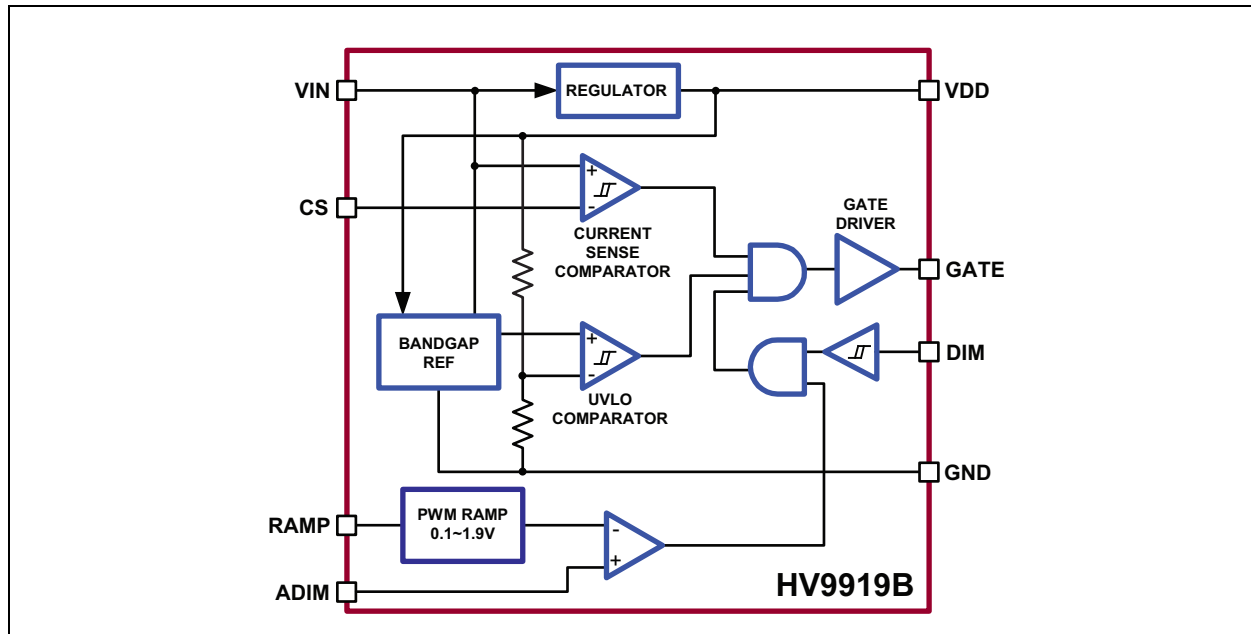
HV9919B comes in a small, 8-Lead DFN package and is ideal for industrial and general lighting applications.

### Package Type

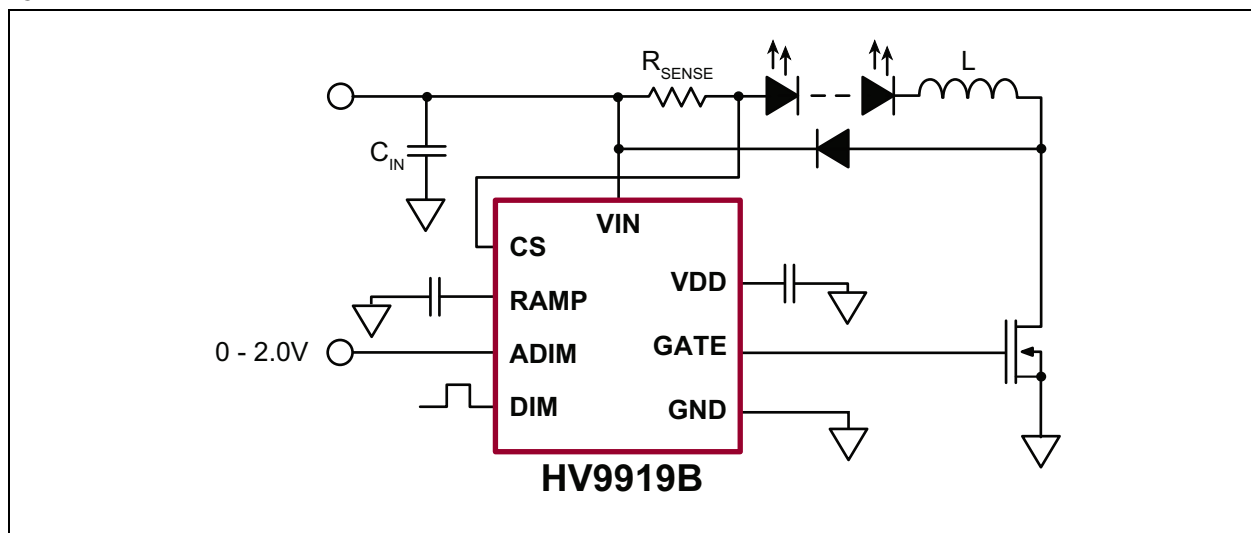


# HV9919B

## Block Diagram



## Typical Application Circuit



## 1.0 ELECTRICAL CHARACTERISTICS

### ABSOLUTE MAXIMUM RATINGS†

|                                                                       |                     |
|-----------------------------------------------------------------------|---------------------|
| $V_{IN}$ to GND .....                                                 | -0.3V to +45V       |
| $V_{DD}$ to GND .....                                                 | -0.3V to +6.0V      |
| GATE, RAMP, DIM, ADIM to GND .....                                    | -0.3V to + $V_{DD}$ |
| CS to $V_{IN}$ .....                                                  | -1.0V to +0.3V      |
| Continuous total power dissipation ( $T_A = 25^\circ\text{C}$ ) ..... | 1.6W                |
| Operating temperature range .....                                     | -40°C to +125°C     |
| Junction temperature .....                                            | +150°C              |
| Storage temperature range .....                                       | -65°C to +150°C     |

† **Notice:** Stresses above those listed under “Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

**TABLE 1-1: ELECTRICAL CHARACTERISTICS (SHEET 1 OF 2)**

| <b>Electrical Specifications:</b> $V_{IN}=12\text{V}$ , $V_{DIM} = V_{DD}$ , $V_{RAMP} = \text{GND}$ , $C_{VDD} = 1.0\ \mu\text{F}$ , $R_{CS} = 0.5\Omega$ , $T_A = T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , unless otherwise noted. ( <a href="#">Note 1</a> ) |                     |     |     |     |               |                                                                                |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------|-----|-----|-----|---------------|--------------------------------------------------------------------------------|
| Parameter                                                                                                                                                                                                                                                                 | Symbol              | Min | Typ | Max | Units         | Conditions                                                                     |
| Input DC supply voltage range                                                                                                                                                                                                                                             | $V_{IN}$            | 4.5 | -   | 40  | V             | DC input voltage                                                               |
| Internally regulated voltage                                                                                                                                                                                                                                              | $V_{DD}$            | 4.5 | -   | 5.5 | V             | $V_{IN}= 6.0$ to $40\text{V}$                                                  |
| Supply current                                                                                                                                                                                                                                                            | $I_{IN}$            | -   | -   | 1.5 | mA            | GATE open                                                                      |
| Shutdown supply current                                                                                                                                                                                                                                                   | $I_{IN, SDN}$       | -   | -   | 900 | $\mu\text{A}$ | $\text{DIM} < 0.7\text{V}$                                                     |
| Current limit                                                                                                                                                                                                                                                             | $I_{IN, LIM}$       | -   | 11  | -   | mA            | $V_{IN}= 4.5\text{V}$ , $V_{DD}= 0\text{V}$                                    |
|                                                                                                                                                                                                                                                                           |                     | -   | 5.5 | -   |               | $V_{IN}= 4.5\text{V}$ , $V_{DD}= 4.0\text{V}$                                  |
| Switching frequency                                                                                                                                                                                                                                                       | $f_{SW}$            | -   | -   | 2.0 | MHz           | —                                                                              |
| $V_{DD}$ Undervoltage lockout threshold                                                                                                                                                                                                                                   | UVLO                | -   | -   | 4.5 | V             | $V_{DD}$ rising                                                                |
| $V_{DD}$ Undervoltage lockout hysteresis                                                                                                                                                                                                                                  | $\Delta\text{UVLO}$ | -   | 500 | -   | mV            | $V_{DD}$ falling                                                               |
| <b>Sense Comparator</b>                                                                                                                                                                                                                                                   |                     |     |     |     |               |                                                                                |
| Sense voltage threshold high                                                                                                                                                                                                                                              | $V_{CS(HI)}$        | -   | 230 | -   | mV            | $(V_{IN} - V_{CS})$ rising                                                     |
| Sense voltage threshold low                                                                                                                                                                                                                                               | $V_{CS(LO)}$        | -   | 170 | -   | mV            | $(V_{IN} - V_{CS})$ falling                                                    |
| Average sense voltage                                                                                                                                                                                                                                                     | $V_{CS(AVG)}$       | 186 | 200 | 214 | mV            | $V_{CS(AVG)} = 0.5(V_{CS(HI)} + V_{CS(LO)})$                                   |
| Propagation delay to output high                                                                                                                                                                                                                                          | $t_{DPDH}$          | -   | 70  | -   | ns            | Falling edge of $(V_{IN} - V_{CS}) = V_{RS(LO)} - 70\text{mV}$                 |
| Propagation delay to output low                                                                                                                                                                                                                                           | $t_{DPDL}$          | -   | 70  | -   | ns            | Rising edge of $(V_{IN} - V_{CS}) = V_{RS(HI)} + 70\text{mV}$                  |
| Current-sense input current                                                                                                                                                                                                                                               | $I_{CS}$            | -   | -   | 1.0 | $\mu\text{A}$ | $(V_{IN} - V_{CS}) = 200\text{mV}$                                             |
| Current-sense threshold hysteresis                                                                                                                                                                                                                                        | $V_{CS(HYS)}$       | 15  | 56  | 98  | mV            | $V_{CS(HYS)} = V_{CS(HI)} - V_{CS(LO)}$                                        |
| <b>DIM Input</b>                                                                                                                                                                                                                                                          |                     |     |     |     |               |                                                                                |
| Pin DIM input high voltage                                                                                                                                                                                                                                                | $V_{IH}$            | 2.2 | -   | -   | V             | —                                                                              |
| Pin DIM input low voltage                                                                                                                                                                                                                                                 | $V_{IL}$            | -   | -   | 0.7 | V             | —                                                                              |
| Turn-on time                                                                                                                                                                                                                                                              | $t_{ON}$            | -   | 100 | -   | ns            | DIM rising edge to $V_{GATE} = 0.5 \times V_{DD}$ , $C_{GATE} = 2.0\text{nF}$  |
| Turn-off time                                                                                                                                                                                                                                                             | $t_{OFF}$           | -   | 100 | -   | ns            | DIM falling edge to $V_{GATE} = 0.5 \times V_{DD}$ , $C_{GATE} = 2.0\text{nF}$ |

# HV9919B

**TABLE 1-1: ELECTRICAL CHARACTERISTICS (SHEET 2 OF 2)**

| <b>Electrical Specifications:</b> $V_{IN}=12V$ , $V_{DIM} = V_{DD}$ , $V_{RAMP} = GND$ , $C_{VDD} = 1.0 \mu F$ , $R_{CS} = 0.5\Omega$ , $T_A = T_J = -40^\circ C$ to $+125^\circ C$ , unless otherwise noted. ( <b>Note 1</b> ) |                   |              |     |      |            |                                         |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|--------------|-----|------|------------|-----------------------------------------|
| Parameter                                                                                                                                                                                                                       | Symbol            | Min          | Typ | Max  | Units      | Conditions                              |
| <b>GATE Driver</b>                                                                                                                                                                                                              |                   |              |     |      |            |                                         |
| GATE current, source                                                                                                                                                                                                            | $I_{GATE}$        | 0.3          | 0.5 | -    | A          | $V_{GATE} = GND$ , ( <b>Note 2</b> )    |
| GATE current, sink                                                                                                                                                                                                              |                   | 0.7          | 1.0 | -    | A          | $V_{GATE} = V_{DD}$ , ( <b>Note 2</b> ) |
| GATE output rise time                                                                                                                                                                                                           | $T_{RISE}$        | -            | 40  | 55   | ns         | $C_{GATE} = 2.0nF$                      |
| GATE output fall time                                                                                                                                                                                                           | $T_{FALL}$        | -            | 17  | 25   | ns         | $C_{GATE} = 2.0nF$                      |
| GATE high output voltage                                                                                                                                                                                                        | $V_{GATE(HI)}$    | $V_{DD}-0.5$ | -   | -    | V          | $I_{GATE} = 10mA$                       |
| GATE low output voltage                                                                                                                                                                                                         | $V_{GATE(LO)}$    | -            | -   | 0.5  | V          | $I_{GATE} = -10mA$                      |
| <b>Over-Temperature Protection</b>                                                                                                                                                                                              |                   |              |     |      |            |                                         |
| Over temperature trip limit                                                                                                                                                                                                     | $T_{OT}$          | 128          | 140 | -    | $^\circ C$ | ( <b>Note 2</b> )                       |
| Temperature hysteresis                                                                                                                                                                                                          | $\Delta T_{HYST}$ | -            | 60  | -    | $^\circ C$ | ( <b>Note 2</b> )                       |
| <b>Analog Control of PWM Dimming</b>                                                                                                                                                                                            |                   |              |     |      |            |                                         |
| Dimming frequency                                                                                                                                                                                                               | $f_{RAMP}$        | 114          | -   | 308  | Hz         | $C_{RAMP} = 47nF$                       |
|                                                                                                                                                                                                                                 |                   | 529          | -   | 1380 |            | $C_{RAMP} = 10nF$                       |
| RAMP threshold, Low                                                                                                                                                                                                             | $V_{LOW}$         | -            | 0.1 | -    | V          | -                                       |
| RAMP threshold, High                                                                                                                                                                                                            | $V_{HIGH}$        | 1.8          | -   | 2.1  | V          | -                                       |
| ADIM offset voltage                                                                                                                                                                                                             | $V_{OS}$          | -35          | -   | +35  | mV         | -                                       |

**Note 1:** Specification is obtained by characterization and is 100% tested at  $T_A = 25^\circ C$ .

**2:** Specification is obtained by characterization and not 100% tested

## TEMPERATURE SPECIFICATIONS

| <b>Electrical Specifications:</b> Unless otherwise specified, for all specifications $T_A = T_J = +25^\circ C$ |               |     |     |     |              |                                                |
|----------------------------------------------------------------------------------------------------------------|---------------|-----|-----|-----|--------------|------------------------------------------------|
| Parameter                                                                                                      | Symbol        | Min | Typ | Max | Units        | Conditions                                     |
| <b>Temperature Ranges</b>                                                                                      |               |     |     |     |              |                                                |
| Operating Temperature                                                                                          |               | -40 |     | 125 | $^\circ C$   |                                                |
| Storage Temperature                                                                                            |               | -65 | -   | 150 | $^\circ C$   |                                                |
| <b>Package Thermal Resistances</b>                                                                             |               |     |     |     |              |                                                |
| Thermal Resistance, DFN                                                                                        | $\theta_{ja}$ | -   | 60  | -   | $^\circ C/W$ | Mounted on FR-4 board, 25 mm x 25 mm x 1.57 mm |

## 2.0 PIN DESCRIPTION

The locations of the pins are listed in [Features](#).

**TABLE 2-1: PIN DESCRIPTION**

| Pin # | Symbol | Description                                                                              |
|-------|--------|------------------------------------------------------------------------------------------|
| 1     | CS     | Current sense input. Senses LED string current.                                          |
| 2     | VIN    | Input voltage 4.5 to 40V DC.                                                             |
| 3     | RAMP   | Analog PWM dimming ramp output.                                                          |
| 4     | ADIM   | Analog 0~2.0V signal input for analog control of PWM dimming.                            |
| 5     | DIM    | PWM signal input.                                                                        |
| 6     | VDD    | Internally regulated supply voltage. Connect a capacitor from V <sub>DD</sub> to ground. |
| 7     | GND    | Device ground.                                                                           |
| 8     | GATE   | Drives gate of external MOSFET.                                                          |
| TAB   | GND    | Must be wired to pin 7 on PCB.                                                           |

# HV9919B

## 3.0 APPLICATION INFORMATION

HV9919B is a step-down, constant current, High-Brightness LED (HB LED) driver. The device operates from a 4.5 to 40V input voltage range and provides the gate drive output to an external N-channel MOSFET.

A high-side, current-sense resistor sets the output current and a dedicated PWM Dimming Input (DIM) allows for a wide range of dimming duty ratios. The PWM dimming could also be achieved by applying a DC voltage between 0 and 2.0V to the Analog Dimming Input (ADIM). In this case, the dimming frequency can be programmed using a single capacitor at the RAMP pin.

The high-side current setting and sensing scheme minimizes the number of external components while delivering LED current with a  $\pm 8\%$  accuracy, using a 1% sense resistor.

### 3.1 Undervoltage Lockout (UVLO)

HV9919B includes a 3.7V Under-Voltage lockout (UVLO) with 500mV hysteresis. When  $V_{DD}$  falls below 3.7V, GATE goes low, turning off the external N-channel MOSFET. GATE goes high once  $V_{DD}$  is 4.5V or higher.

### 3.2 5.0V Regulator

$V_{DD}$  is the output of a 5.0V regulator capable of sourcing 5.0 mA. Bypass  $V_{DD}$  to GND with a 1.0 $\mu$ F capacitor.

### 3.3 DIM Input

HV9919B allows dimming with a PWM signal at the DIM input. A logic level below 0.7V at DIM forces the GATE output low, turning off the LED current. To turn the LED current on, the logic level at DIM must be at least 2.2V.

### 3.4 ADIM and RAMP Inputs

The PWM dimming scheme can be also implemented by applying an analog control signal to ADIM pin. If an analog control signal of 0 – 2.0V is applied to ADIM, the device compares this analog input to a voltage ramp to pulse-width-modulate the LED current. Connecting an external capacitor to RAMP programs the PWM dimming ramp frequency.

$$f_{PWM} = \frac{1}{C_{RAMP} \cdot 120K\Omega}$$

DIM and ADIM inputs can be used simultaneously. In such a case,  $f_{PWM(MAX)}$  must be selected lower than the frequency of the dimming signal at DIM. The smaller dimming duty cycle of ADIM and DIM will determine the GATE signal.

When the analog control of PWM dimming feature is not used, RAMP must be wired to GND, and ADIM should be connected to  $V_{DD}$ .

One possible application of the ADIM feature of HV9919B may include protection of the LED load from over-temperature by connecting an NTC thermistor at ADIM, as shown in Figure 3-1

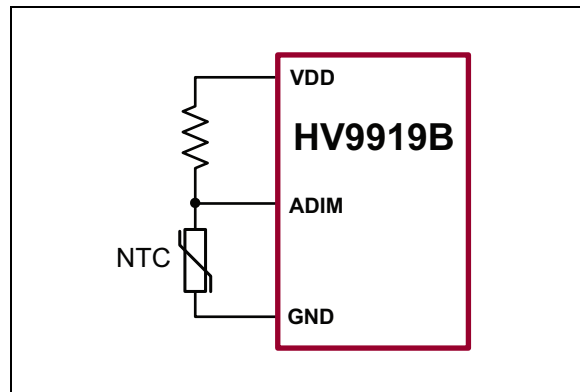


FIGURE 3-1: NTC Thermistor at ADIM

### 3.5 Setting LED Current with External Resistor $R_{SENSE}$

The output current in the LED is determined by the external current sense resistor ( $R_{SENSE}$ ) connected between  $V_{IN}$  and CS. Disregarding the effect of the propagation delays, the sense resistor can be calculated as:

$$R_{SENSE} \approx \frac{1}{2} \cdot \frac{(V_{CS(HI)} + V_{CS(LO)})}{I_{LED}} = \frac{200mV}{I_{LED}}$$

### 3.6 Selecting Buck Inductor L

HV9919B regulates the LED output current using a comparator with hysteresis, see Figure 3-2. As the current through the inductor ramps up and the voltage across the sense resistor reaches the upper threshold, the voltage at GATE goes low, turning off the external MOSFET. The MOSFET turns on again when the inductor current ramps down through the freewheeling diode, until the voltage across the sense resistor equals the lower threshold. Use the following equation to determine the inductor value for a desired value of operating frequency  $f_S$ :

$$L = \frac{(V_{IN} - V_{OUT})V_{OUT}}{f_S V_{IN} \Delta I_O} - \frac{V_{IN} - V_{OUT} t_{DPDL}}{\Delta I_O} - \frac{V_{OUT} t_{DPDH}}{\Delta I_O}$$

Where:

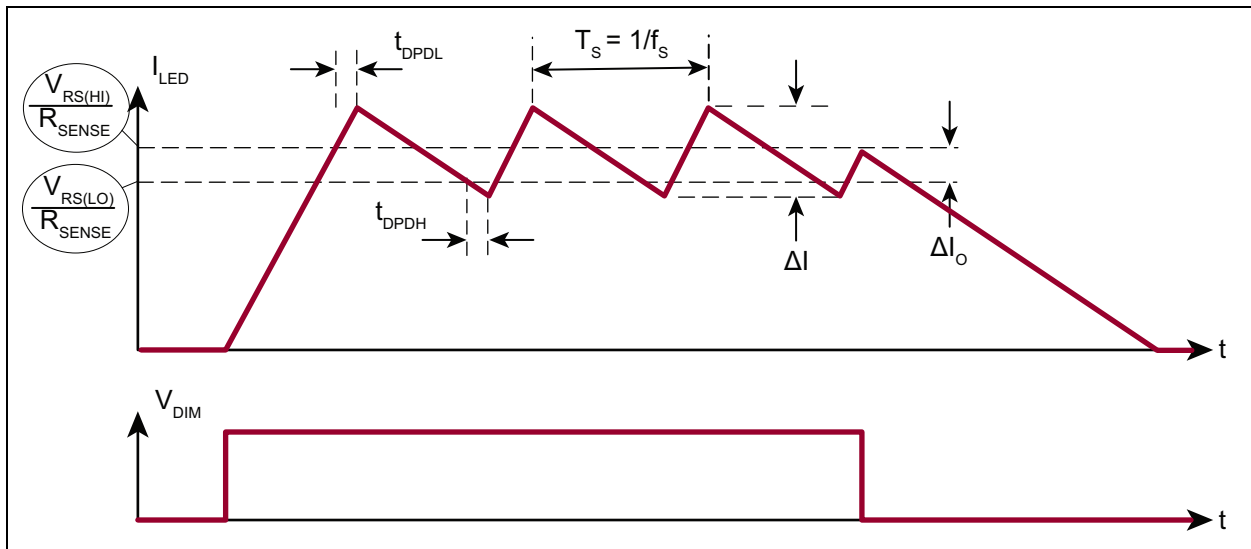
$$\Delta I_O = \frac{V_{CS(HI)} - V_{CS(LO)}}{R_{SENSE}}$$

and  $t_{DPDL}$ ,  $t_{DPDH}$  are the propagation delays. The current ripple  $\Delta I$  in the inductor  $L$  is greater than  $\Delta I_O$ .

This ripple can be calculated from the following equation:

$$\Delta I = \Delta I_O + \frac{(V_{IN} - V_{OUT})t_{DPDL}}{L} + \frac{V_{OUT}t_{DPDH}}{L}$$

For the purpose of the proper inductor selection, note that the maximum switching frequency occurs at the highest  $V_{IN}$  and  $V_{OUT} = V_{IN}/2$ .



**FIGURE 3-2:** Regulating LED output

### 3.7 MOSFET Selection

MOSFET selection is based on the maximum input operating voltage  $V_{IN}$ , output current  $I_{LED}$ , and operating switching frequency. Choose a logic-level MOSFET that has a higher breakdown voltage than the maximum operation voltage, low  $R_{DS(ON)}$ , and low total gate charge for better efficiency.

### 3.8 Freewheeling Diode Selection

The forward voltage of the freewheeling diode should be as low as possible for better efficiency. A Schottky diode is a good choice as long as the breakdown voltage is high enough to withstand the maximum operating voltage. The forward-current rating of the diode must be at least equal to the maximum LED current.

### 3.9 LED Current Ripple

The LED current ripple is equal to the inductor-current ripple. In cases when a lower LED current ripple is needed, a capacitor can be placed across the LED terminals.

### 3.10 PCB Layout Guidelines

Careful PCB layout is critical to achieve low switching losses and stable operation. Use a multilayer board whenever possible for better noise immunity. Minimize ground noise by connecting high-current ground returns, the input bypass capacitor ground lead, and the output filter ground lead to a single point (star ground configuration). The fast di/dt loop is formed by the input capacitor  $C_{IN}$ , the free-wheeling diode and the MOSFET. To minimize noise interaction, this loop area should be as small as possible. Place  $R_{SENSE}$  as close as possible to the input filter and  $V_{IN}$ . For better noise immunity, a Kelvin connection is strongly recommended between CS and  $R_{SENSE}$ . Connect the exposed tab of the IC to a large-area ground plane for improved power dissipation.

## 4.0 PACKAGING INFORMATION

### 4.1 Package Marking Information

8-lead DFN

Example

XXXX  
YYWW  
○NNN

9919  
1542  
○343

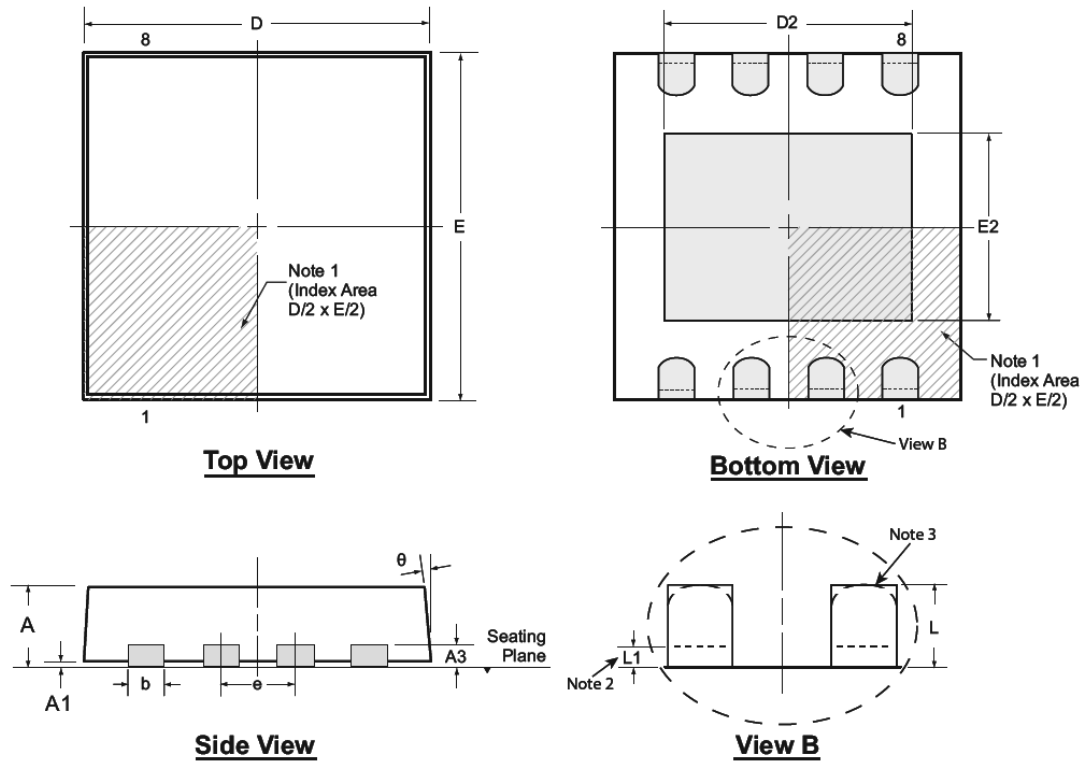
**Legend:**  
XX...X  
Y  
YY  
WW  
NNN  
ⓔ3  
\*

Product Code or Customer-specific information  
Year code (last digit of calendar year)  
Year code (last 2 digits of calendar year)  
Week code (week of January 1 is week '01')  
Alphanumeric traceability code  
Pb-free JEDEC® designator for Matte Tin (Sn)  
This package is Pb-free. The Pb-free JEDEC designator ⓔ3 can be found on the outer packaging for this package.

**Note:** In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for product code or customer-specific information. Package may or not include the corporate logo.

## 8-Lead DFN Package Outline (K7)

3.00x3.00mm body, 0.80mm height (max), 0.65mm pitch



Note: For the most current package drawings, see the Microchip Packaging Specification at [www.microchip.com/packaging](http://www.microchip.com/packaging).

### Notes:

1. A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.
2. Depending on the method of manufacturing, a maximum of 0.15mm pullback (L1) may be present.
3. The inner tip of the lead may be either rounded or square.

| Symbol         | A   | A1   | A3   | b    | D     | D2   | E     | E2   | e        | L    | L1    | θ   |
|----------------|-----|------|------|------|-------|------|-------|------|----------|------|-------|-----|
| Dimension (mm) | MIN | 0.70 | 0.00 | 0.25 | 2.85* | 1.60 | 2.85* | 1.35 | 0.65 BSC | 0.30 | 0.00* | 0°  |
|                | NOM | 0.75 | 0.02 | 0.30 | 3.00  | -    | 3.00  | -    |          | 0.40 | -     | -   |
|                | MAX | 0.80 | 0.05 | 0.35 | 3.15* | 2.50 | 3.15* | 1.75 |          | 0.50 | 0.15  | 14° |

JEDEC Registration MO-229, Variation WEEC-2, Issue C, Aug. 2003.

\* This dimension is not specified in the JEDEC drawing.

Drawings not to scale.

## APPENDIX A: REVISION HISTORY

### Revision A (November 2015)

- Updated file to Microchip format.
- Revised [Absolute Maximum Ratings<sup>†</sup>](#).
- Modified values and notes in [Table 1-1](#).
- Added condition to [Temperature Specifications](#).
- Changed value in [Section 3.2 “5.0V Regulator”](#).
- Wording change in [Section 3.7 “MOSFET Selection”](#).
- Minor text changes throughout.

### Revision B (December 2015)

- Updated Revision History.

## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

| <u>PART NO.</u> |                                                                                       | <u>XX</u>                               | - | <u>X</u>   | - | <u>X</u> |
|-----------------|---------------------------------------------------------------------------------------|-----------------------------------------|---|------------|---|----------|
| Device          | Package Options                                                                       | Environmental                           |   | Media Type |   |          |
| Device:         | HV9919B = Hysteretic, Buck, High Brightness LED Driver with High-Side Current Sensing |                                         |   |            |   |          |
| Package:        | K7                                                                                    | = 48-lead DFN                           |   |            |   |          |
| Environmental   | G                                                                                     | = Lead (Pb)-free/ROHS-compliant package |   |            |   |          |
| Media Type:     | (blank)                                                                               | = 3000/Reel                             |   |            |   |          |

**Examples:**

a) HV9919BK7-G      8-Lead DFN package, 3000/Reel

### Examples:

a) HV9919BK7-G      8-Lead DFN package,  
3000/Reel

---

**Note the following details of the code protection feature on Microchip devices:**

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

#### **Trademarks**

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, flexPWR, JukeBlox, KEELOQ, KEELOQ logo, Klear, LANCheck, MediaLB, MOST, MOST logo, MPLAB, OptoLyzer, PIC, PICSTART, PIC<sup>32</sup> logo, RightTouch, SpyNIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

The Embedded Control Solutions Company and mTouch are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, ECAN, In-Circuit Serial Programming, ICSP, Inter-Chip Connectivity, KlearNet, KlearNet logo, MiWi, motorBench, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICTail, RightTouch logo, REAL ICE, SQI, Serial Quad I/O, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2015, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-5224-0111-7

**QUALITY MANAGEMENT SYSTEM**  
**CERTIFIED BY DNV**  
**== ISO/TS 16949 ==**

*Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.*

## Worldwide Sales and Service

### AMERICAS

**Corporate Office**  
2355 West Chandler Blvd.  
Chandler, AZ 85224-6199  
Tel: 480-792-7200  
Fax: 480-792-7277  
Technical Support:  
<http://www.microchip.com/support>  
Web Address:  
[www.microchip.com](http://www.microchip.com)

**Atlanta**  
Duluth, GA  
Tel: 678-957-9614  
Fax: 678-957-1455

**Austin, TX**  
Tel: 512-257-3370

**Boston**  
Westborough, MA  
Tel: 774-760-0087  
Fax: 774-760-0088

**Chicago**  
Itasca, IL  
Tel: 630-285-0071  
Fax: 630-285-0075

**Cleveland**  
Independence, OH  
Tel: 216-447-0464  
Fax: 216-447-0643

**Dallas**  
Addison, TX  
Tel: 972-818-7423  
Fax: 972-818-2924

**Detroit**  
Novi, MI  
Tel: 248-848-4000

**Houston, TX**  
Tel: 281-894-5983

**Indianapolis**  
Noblesville, IN  
Tel: 317-773-8323  
Fax: 317-773-5453

**Los Angeles**  
Mission Viejo, CA  
Tel: 949-462-9523  
Fax: 949-462-9608

**New York, NY**  
Tel: 631-435-6000

**San Jose, CA**  
Tel: 408-735-9110

**Canada - Toronto**  
Tel: 905-673-0699  
Fax: 905-673-6509

### ASIA/PACIFIC

**Asia Pacific Office**  
Suites 3707-14, 37th Floor  
Tower 6, The Gateway  
Harbour City, Kowloon

**Hong Kong**  
Tel: 852-2943-5100  
Fax: 852-2401-3431

**Australia - Sydney**  
Tel: 61-2-9868-6733  
Fax: 61-2-9868-6755

**China - Beijing**  
Tel: 86-10-8569-7000  
Fax: 86-10-8528-2104

**China - Chengdu**  
Tel: 86-28-8665-5511  
Fax: 86-28-8665-7889

**China - Chongqing**  
Tel: 86-23-8980-9588  
Fax: 86-23-8980-9500

**China - Dongguan**  
Tel: 86-769-8702-9880

**China - Hangzhou**  
Tel: 86-571-8792-8115  
Fax: 86-571-8792-8116

**China - Hong Kong SAR**  
Tel: 852-2943-5100  
Fax: 852-2401-3431

**China - Nanjing**  
Tel: 86-25-8473-2460  
Fax: 86-25-8473-2470

**China - Qingdao**  
Tel: 86-532-8502-7355  
Fax: 86-532-8502-7205

**China - Shanghai**  
Tel: 86-21-5407-5533  
Fax: 86-21-5407-5066

**China - Shenyang**  
Tel: 86-24-2334-2829  
Fax: 86-24-2334-2393

**China - Shenzhen**  
Tel: 86-755-8864-2200  
Fax: 86-755-8203-1760

**China - Wuhan**  
Tel: 86-27-5980-5300  
Fax: 86-27-5980-5118

**China - Xian**  
Tel: 86-29-8833-7252  
Fax: 86-29-8833-7256

### ASIA/PACIFIC

**China - Xiamen**  
Tel: 86-592-2388138  
Fax: 86-592-2388130

**China - Zhuhai**  
Tel: 86-756-3210040  
Fax: 86-756-3210049

**India - Bangalore**  
Tel: 91-80-3090-4444  
Fax: 91-80-3090-4123

**India - New Delhi**  
Tel: 91-11-4160-8631  
Fax: 91-11-4160-8632

**India - Pune**  
Tel: 91-20-3019-1500

**Japan - Osaka**  
Tel: 81-6-6152-7160  
Fax: 81-6-6152-9310

**Japan - Tokyo**  
Tel: 81-3-6880-3770  
Fax: 81-3-6880-3771

**Korea - Daegu**  
Tel: 82-53-744-4301  
Fax: 82-53-744-4302

**Korea - Seoul**  
Tel: 82-2-554-7200  
Fax: 82-2-558-5932 or  
82-2-558-5934

**Malaysia - Kuala Lumpur**  
Tel: 60-3-6201-9857  
Fax: 60-3-6201-9859

**Malaysia - Penang**  
Tel: 60-4-227-8870  
Fax: 60-4-227-4068

**Philippines - Manila**  
Tel: 63-2-634-9065  
Fax: 63-2-634-9069

**Singapore**  
Tel: 65-6334-8870  
Fax: 65-6334-8850

**Taiwan - Hsin Chu**  
Tel: 886-3-5778-366  
Fax: 886-3-5770-955

**Taiwan - Kaohsiung**  
Tel: 886-7-213-7828

**Taiwan - Taipei**  
Tel: 886-2-2508-8600  
Fax: 886-2-2508-0102

**Thailand - Bangkok**  
Tel: 66-2-694-1351  
Fax: 66-2-694-1350

### EUROPE

**Austria - Wels**  
Tel: 43-7242-2244-39  
Fax: 43-7242-2244-393

**Denmark - Copenhagen**  
Tel: 45-4450-2828  
Fax: 45-4485-2829

**France - Paris**  
Tel: 33-1-69-53-63-20  
Fax: 33-1-69-30-90-79

**Germany - Dusseldorf**  
Tel: 49-2129-3766400

**Germany - Karlsruhe**  
Tel: 49-721-625370

**Germany - Munich**  
Tel: 49-89-627-144-0  
Fax: 49-89-627-144-44

**Italy - Milan**  
Tel: 39-0331-742611  
Fax: 39-0331-466781

**Italy - Venice**  
Tel: 39-049-7625286

**Netherlands - Drunen**  
Tel: 31-416-690399  
Fax: 31-416-690340

**Poland - Warsaw**  
Tel: 48-22-3325737

**Spain - Madrid**  
Tel: 34-91-708-08-90  
Fax: 34-91-708-08-91

**Sweden - Stockholm**  
Tel: 46-8-5090-4654

**UK - Wokingham**  
Tel: 44-118-921-5800  
Fax: 44-118-921-5820